



高速光耦
High Speed Photo Coupler

ATW6XX

Product Data Sheet

AOTE DCC
RELEASE

台湾奥特半导体科技有限公司

TAIWAN AOTE SEMICONDUCTOR TECHNOLOGY CO.,LTD

www.aotesemi.com

概述 Description

ATW600、ATW601、ATW611 内部有一个 850nm 的 AlGaAs LED，其光学耦合到具有选通输出的超高速集成光电检测器。
The ATW600 ATW601 ATW611 optocoupler consists of a 850 nm AlGaAs LED, optically coupled to a very high speed integrated photo-detector logic gate with a strobable output.

特性 Features

- 高速 10 MBit/s
High speed – 10 MBit/s
- 输入-输出高隔离电压 ($V_{ISO}=5000$ Vrms)
High isolation voltage between input and output($V_{ISO}=5000$ Vrms)
- 工作温度：-40°C ~110°C
Operating Temperature: -40°C ~85°C
- 逻辑门输出
Logic gate output
- 符合安规标准：UL 1577，VDE DIN EN60747-5-5 (VDE 0884-5)，CQC11-471543-2022
Meet Safety standard : UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5)，CQC11-471543-2022

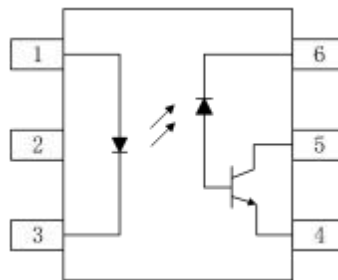
应用 Applications

- 接地回路消除
Ground loop elimination
- 开关电源
Switching power supplies
- 计算机外围接口
Computer-peripheral interface
- LSTTL 转 TTL, LSTTL 或 5V CMOS
LSTTL to TTL, LSTTL or 5-volt CMOS
- 线路接收器，数据传输
Line receiver, data transmission

真值表 Truth table

LED	VO
OFF	H
ON	L

封装和原理图 Package and Schematic Diagram



Pin Configuration

1. Anode
2. NC
3. Cathode
4. GND
5. VO
6. VCC

注：在引脚 4 和 6 之间必须连接一个 0.1uF 的旁路电容器。

Note: 0.1uF bypass capacitor must be connected between pins 4 and 6.



产品型号命名规则 Order Code

AT W6XX - UN Y - W (V) (ZZ)

① ② ③ ④ ⑤ ⑥ ⑦

- ① 公司代码 Company Code (AT: 奥特 Aote)
- ② 产品系列 Product Series (XX: 00, 01, 11)
- ③ 框架类型 Lead Frame (Cu: 铜框架 Copper)
- ④ 树脂类型 Epoxy Type (H: 无卤 Halogen-free)
- ⑤ 封装形式 Package (S: SOP)
- ⑥ 器件工作温度范围 Device Operating Temperature Range (特殊范围需填或者空白 Special Range need to be filled in or left blank)
- ⑦ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

印字信息 Marking Information

- 印字中 “” 为奥特品牌 LOGO
“” denotes LOGO
- 印字中的 “XX” 代表产品分档：00、01、11
“XX” denotes the classification：00、01、11
- 印字中 “Y” 代表年份；A(2018),B(2019),C(2020)
“Y” denotes YEAR：A(2018), B(2019), C(2020)
- 印字中 “WW” 代表周号
“WW” denotes week’s number.
- 印字中 “N” 代表星期几
“N” denotes day of the week.
- 印字中的 “H” 代表无卤
“H” denotes Halogen-free



绝缘和安规信息 Insulation and Safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	>8.0	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	>8.0	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	>0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	V_{IORM}	1500	V_{peak}	DIN/EN/IEC EN60747-5-5
瞬态隔离电压 Transient isolation voltage	V_{IOTM}	7000	V_{peak}	DIN/EN/IEC EN60747-5-5
隔离电压 Isolation Voltage	V_{iso}	>5000	Vrms	For 1 min

极限参数 Absolute Maximum Ratings (Ta = 25°C)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
发射端 Input	正向电流 Forward Current	I_F	50	mA
	反向电压 Reverse Voltage	V_R	5	V
	功耗 Power Dissipation	P_D	100	mW
接收端 Output	电源电压 Supply Voltage	V_{CC}	7.0	V
	输出电流 Output Current	I_O	50	mA
	输出电压 Output Voltage	V_O	7.0	V
	集电极功耗 Collector Power Dissipation	P_C	85	mW
工作温度 Operating Temperature		T_{opr}	-40 ~ +110	°C
存储温度 Storage Temperature		T_{stg}	-55 ~ +125	°C
焊接温度 Soldering Temperature		T_{sol}	260 for 10 sec	°C

推荐工作条件 Recommended Operating Conditions

参数 Parameter	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
电源电压 Supply Voltages	V_{CC}	4.5	5.5	V
高电平输入电流 Input Current, High level	I_{FH}	2	10.0	mA
低电平输入电流 Input Current, Low level	I_{FL}	0	250	μ A
操作温度 Operating Temperature	T_a	-40	+110	$^{\circ}$ C

产品特性参数 Electro-optical Characteristics ($T_a = 25^{\circ}$ C)

参数 Parameter	符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit	
发射端 Input	正向电压 Forward Voltage	V_F	$I_F = 10\text{mA}$	-	1.33	1.8	V
	反向击穿电压 Reverse Breakdown Voltage	BV_R	$I_R = 10\mu\text{A}$	5	20	45	V
	电容 Capacitance	C_{IN}	$V=0, f=1\text{MHz}$	-	70	-	pF
	正向电压的温度系数 Diode Temperature Coefficient	$\Delta V_F / \Delta T_A$	$I_F = 10\text{mA}$	-	-1.9	-	mV/ $^{\circ}$ C
接收端 Output	高电平电源电流 High Level Supply Current	I_{CCH}	$V_{CC} = 5.5\text{V}, I_F = 0\text{mA}$	-	6.0	9	mA
	低电平电源电流 Low Level Supply Current	I_{CCL}	$V_{CC} = 5.5\text{V}, I_F = 0\text{mA}$	-	7.5	10	mA
传输特性 Transfer Characteristics	高电平输出电流 HIGH Level Output Current	I_{OH}	$V_{CC} = 5.5\text{V}$ $V_O = 5.5\text{V}$ $I_F = 250\mu\text{A}$	-	2.1	30	μ A
	低电平输出电压 LOW Level Output Voltage	V_{OL}	$V_{CC} = 5.5\text{V}$ $I_F = 5\text{mA}$ $I_{CL} = 13\text{mA}$	-	0.4	0.6	V
	输入阈值电流 Input Threshold Current	I_{TH}	$V_{CC} = 5.5\text{V}$ $V_O = 0.6\text{V}$ $I_{OL} = 13\text{mA}$	-	2.4	5	mA
隔离电压 Isolation Voltage	V_{ISO}	$R_H < 50\%$ $T_A = 25^{\circ}\text{C}$ $I_{IO} \leq 50\mu\text{A}$	5000	-	-	V_{RMS}	
电阻 (输入到输出) Resistance (Input to Output)	R_{I-O}	$V_{I-O} = 500\text{V}$	-	10^{12}	-	Ω	
电容 (输入到输出) Resistance (Input to Output)	C_{I-O}	$f = 1\text{MHz}$	-	0.6	-	pF	

开关特性 Switching Specification (Ta = 25°C, I_F = 7.5 mA, V_{CC} = 5.0V)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit
输出高电平传播延迟 Propagation Delay Time to High Output Level		T _{PLH}	C _L =15pF R _L =350Ω T _A =25°C	-	41	100	ns
输出低电平传播延迟 Propagation Delay Time to Low Output Level		T _{PHL}		-	50	100	ns
脉宽失真 Pulse Width Distortion		T _{PHL} - T _{PLH}		-	9	35	ns
输出上升时间(10% – 90%) Output Rise Time (10 to 90%)		t _r		-	40	-	ns
输出下降时间(90% - 10%) Output Fall Time (90 to 10%)		t _f		-	10	-	ns
传播延迟偏斜 Propagation Delay Skew		t _{psk}		-	-	40	ns
输出高电平共模瞬态抑制 Common Mode Transient Immunity at High Output Level	W600	CM _H	T _A =25°C, I _F =0mA V _{CM} =10V(Peak) V _{OH} =2.0V, R _L =350Ω	-	-	-	V/μs
	W601		T _A =25°C, I _F =0mA V _{CM} =50V(Peak) V _{OH} =2.0V, R _L =350Ω	5000	-	-	
	W611		T _A =25°C, I _F =0mA V _{CM} =1000V(Peak) V _{OH} =2.0V, R _L =350Ω	20000	-	-	
输出低电平共模瞬态抑制 Common Mode Transient Immunity at Low Output Level	W600	CM _L	I _F =7.5mA, V _{OL} =0.8V R _L =350Ω, T _A =25°C V _{CM} =10V(Peak)	-	-	-	V/μs
	W601		I _F =7.5mA, V _{OL} =0.8V R _L =350Ω, T _A =25°C V _{CM} =50V(Peak)	5000	-	-	
	W611		I _F =7.5mA, V _{OL} =0.8V R _L =350Ω, T _A =25°C V _{CM} =1000V(Peak)	20000	-	-	

典型光电特性曲线 Typical Electro-Optical Characteristics Curves

Fig.1 Low-level voltage vs. Ambient temperature

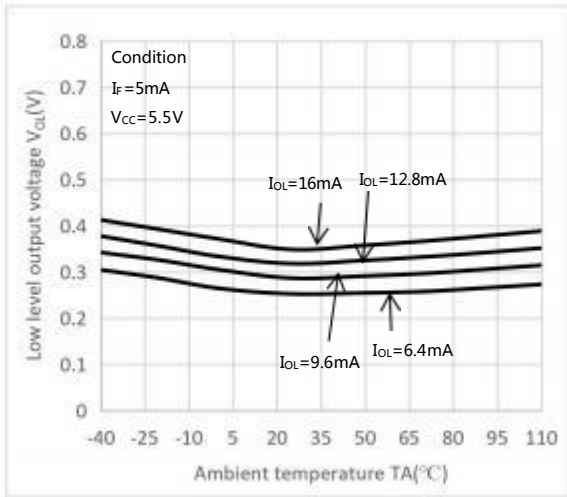


Fig.2 Forward current voltage vs. Forward voltage

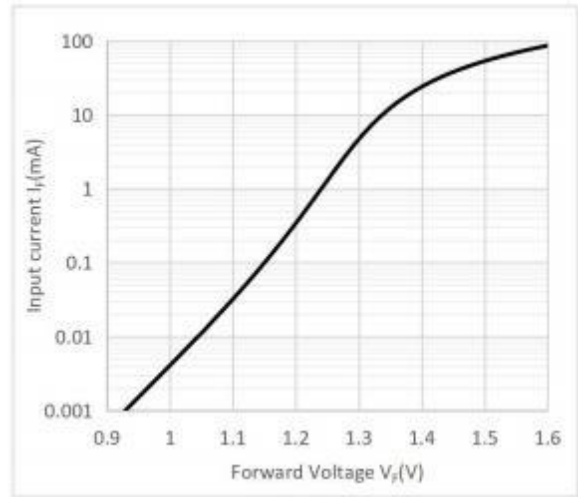


Fig.3 Switch time vs. Forward current

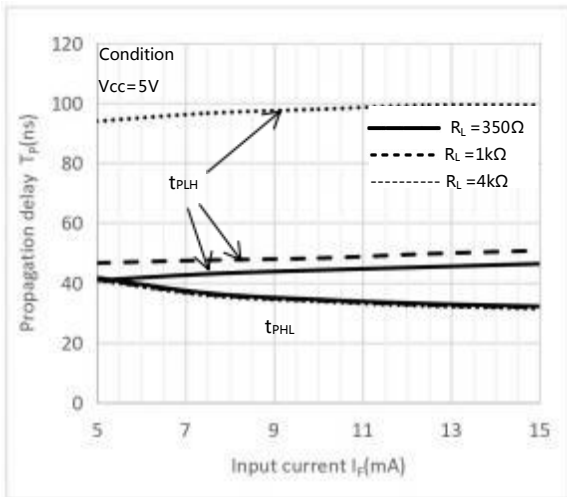


Fig.4 Low-level output current vs. Ambient temperature

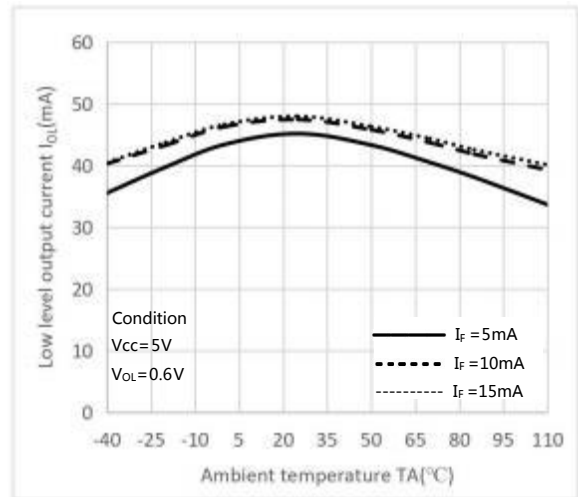


Fig.5 Input Threshold Current vs. Ambient temperature

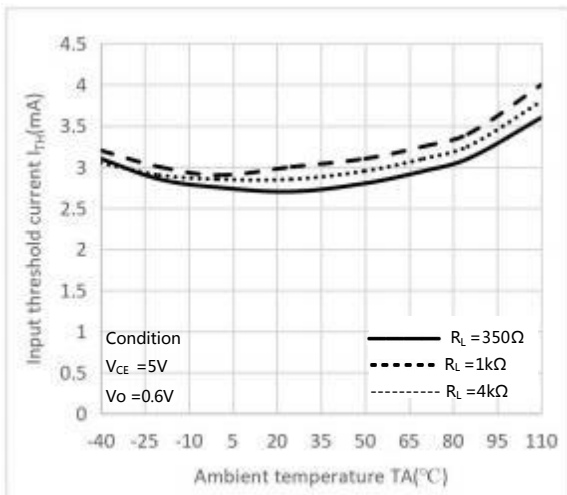


Fig.6 Output voltage vs. Input Forward current

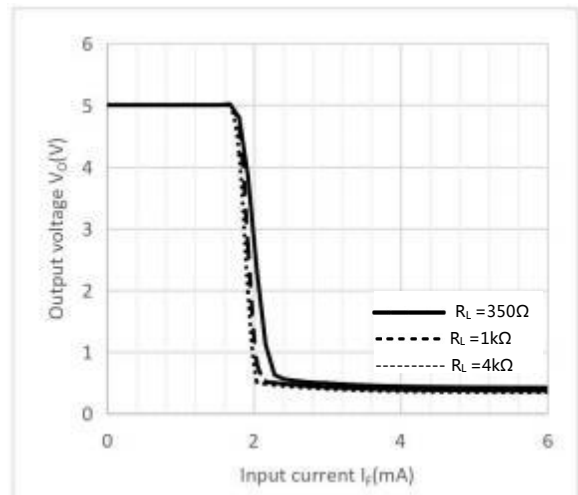


Fig.7 Pulse-width distortion vs. Ambient temperature

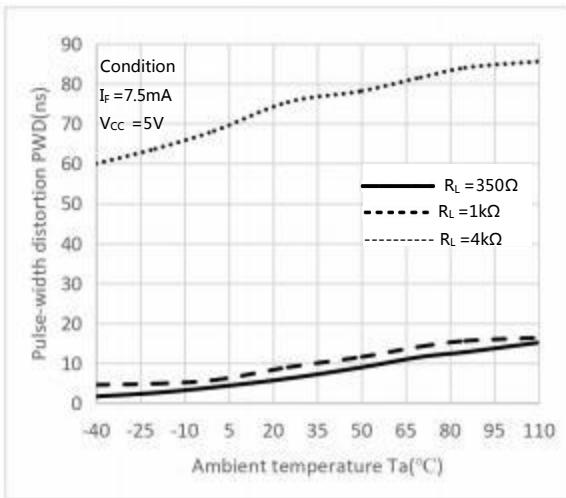


Fig.8 Switch time vs. Ambient temperature

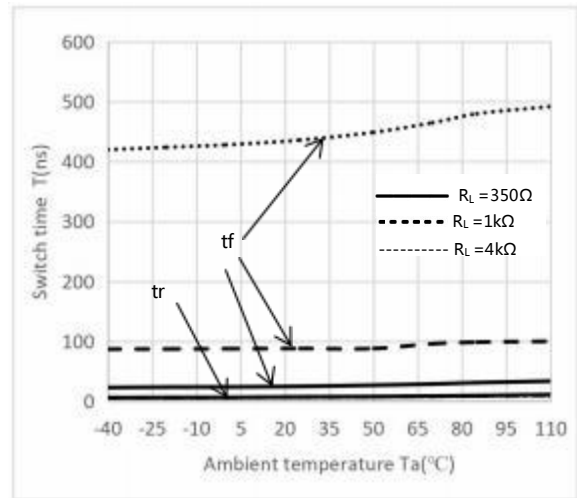


Fig.9 Propagation delay vs. Ambient temperature

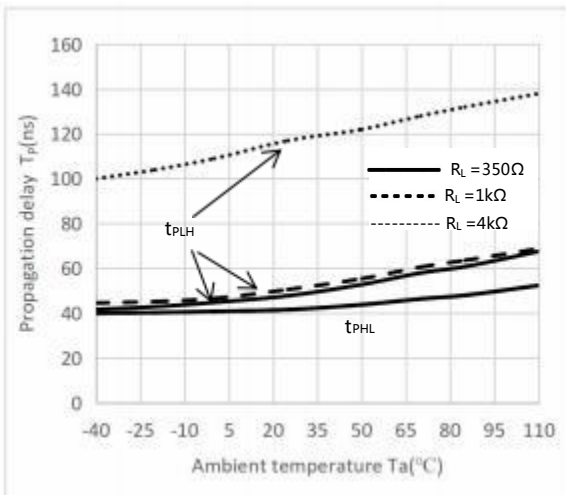
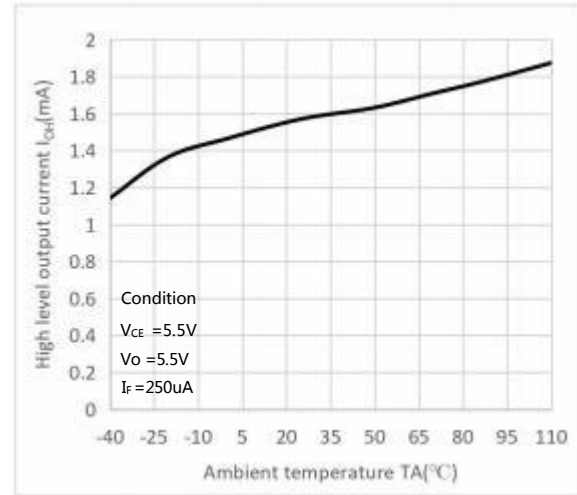
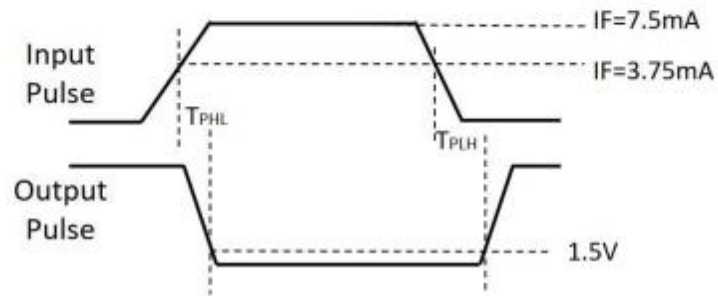
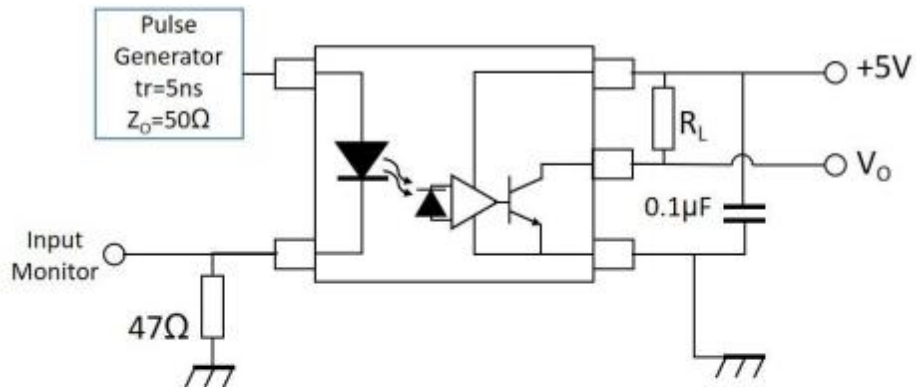


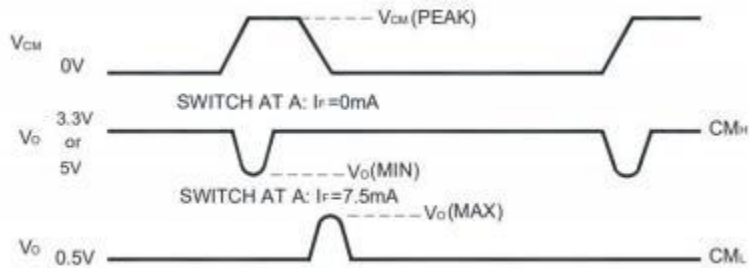
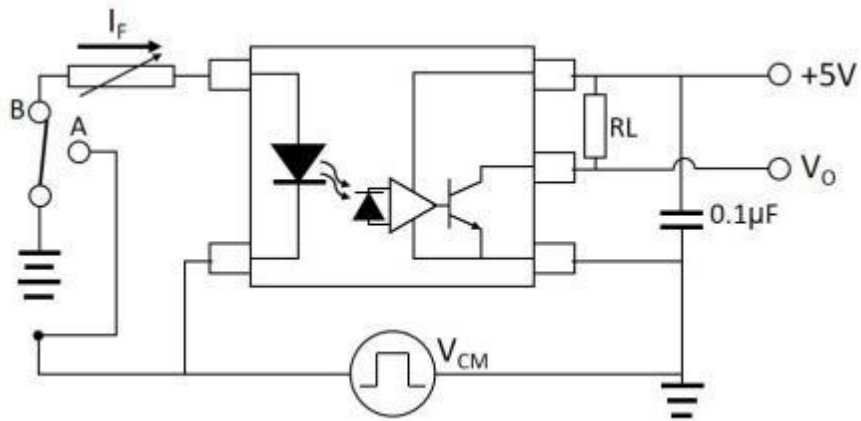
Fig.10 High-level output current vs. Ambient temperature



开关时间测试电路 Witch Time Test Circuit

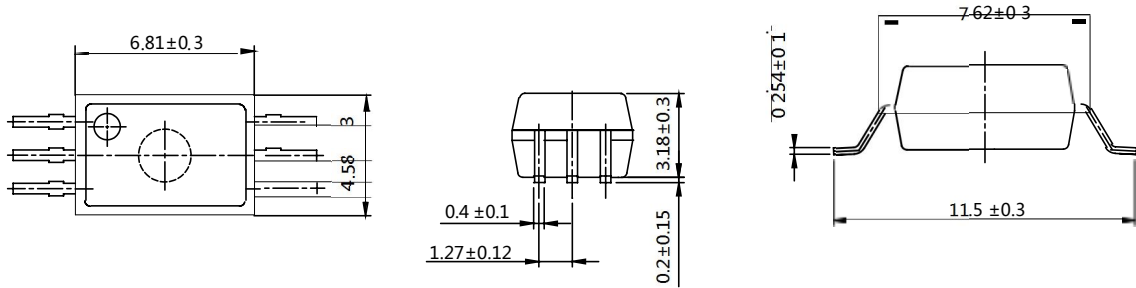


CMR 测试电路 Test Circuit for Common Mode Transient Immunity

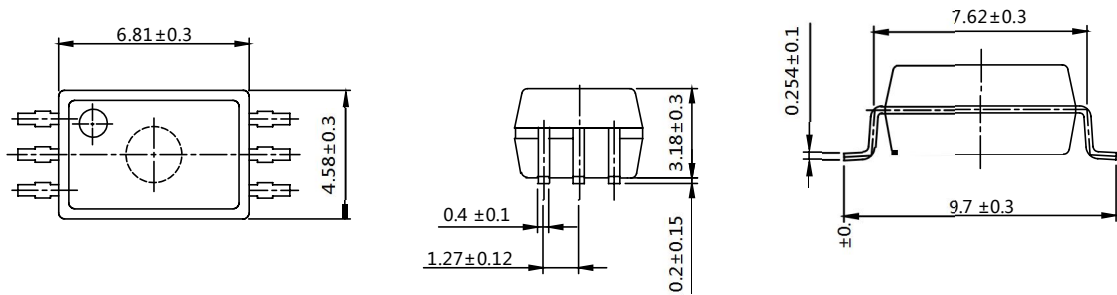


外形尺寸 Outline Dimensions

SOP6-W

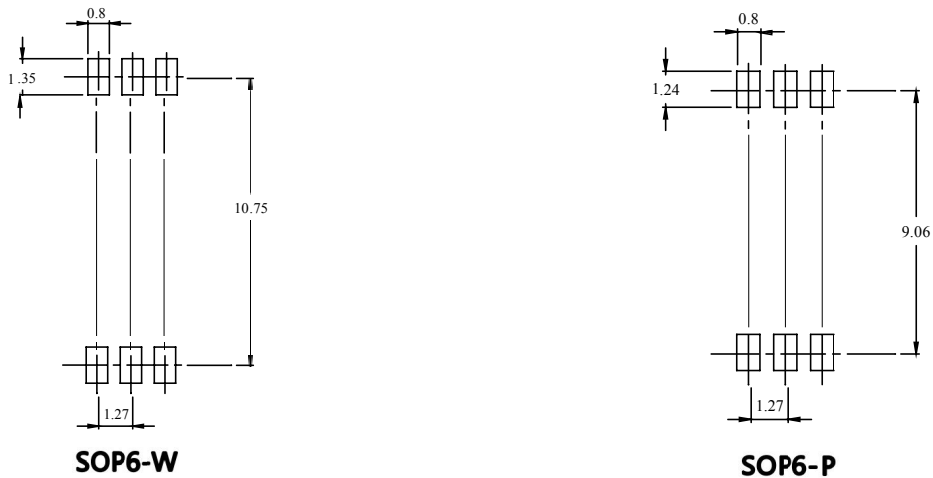


SOP6-P



单位 Unit: mm

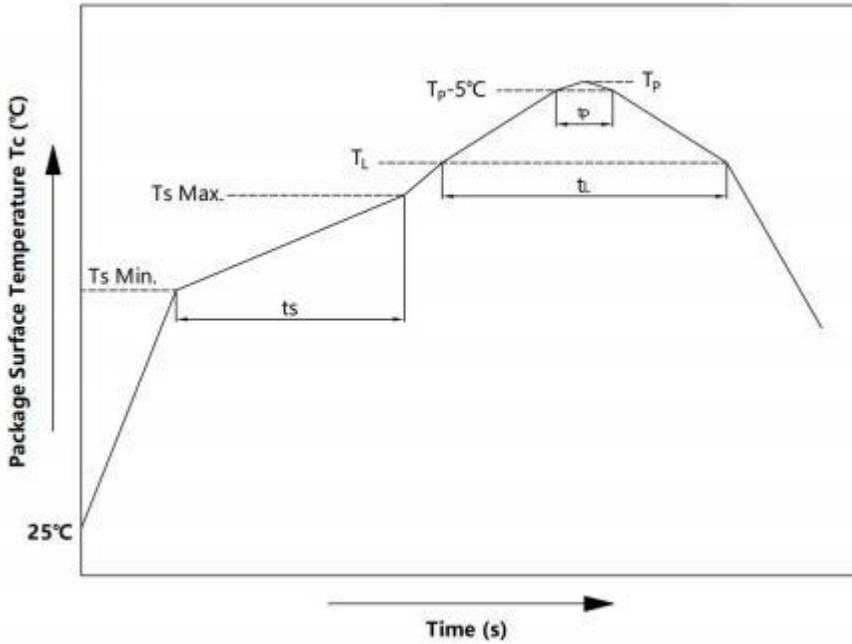
建议焊盘布局 Recommended Pad Layout



单位 Unit: mm

注：上图为产品正视图。

Note: The picture above is the front view of the product.

回流焊温度曲线图 Solder Reflow Profile


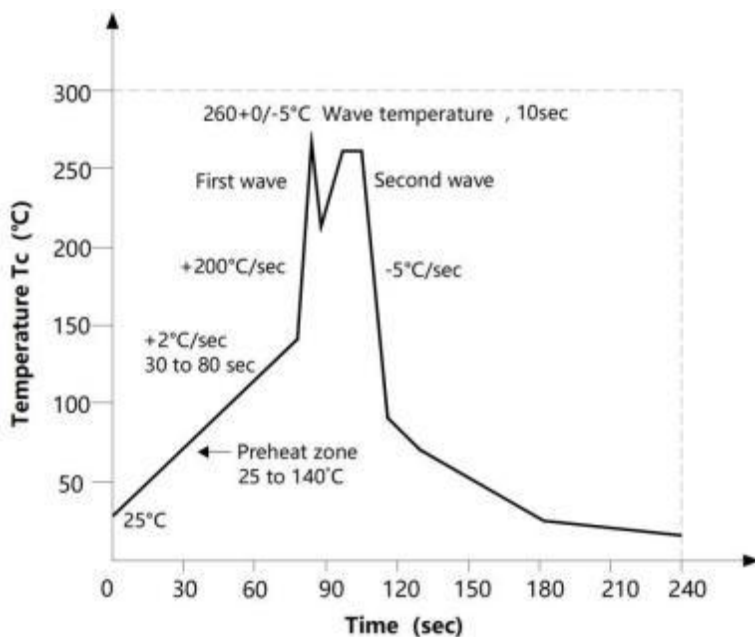
项目 Item	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
预热温度 Preheat Temperature	Ts	150	200	°C
预热时间 Preheat Time	ts	60	120	s
升温速率 Ramp-Up Rate (T _L to T _P)	-	-	3	°C/s
液相线温度 Liquidus Temperature	T _L	217		°C
时间高于 T _L Time Above T _L	t _L	60	150	s
峰值温度 Peak Temperature	T _P	-	260	°C
Tc 在(T _P -5)和 T _P 之间的时间 Time During Which Tc Is Between (T _P -5) and T _P	t _p	-	30	s
降温速率 Ramp-down Rate(T _P to T _L)	-	-	6	°C/s

注 Note :

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 Wave Soldering Profile



手工烙铁焊接 Soldering with hand soldering iron

- A. 手工烙铁焊仅用于产品返修或样品测试；
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求：温度 $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ ，时间 $\leq 3\text{s}$ 。
Hand soldering iron requirements：Temperature： $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s.

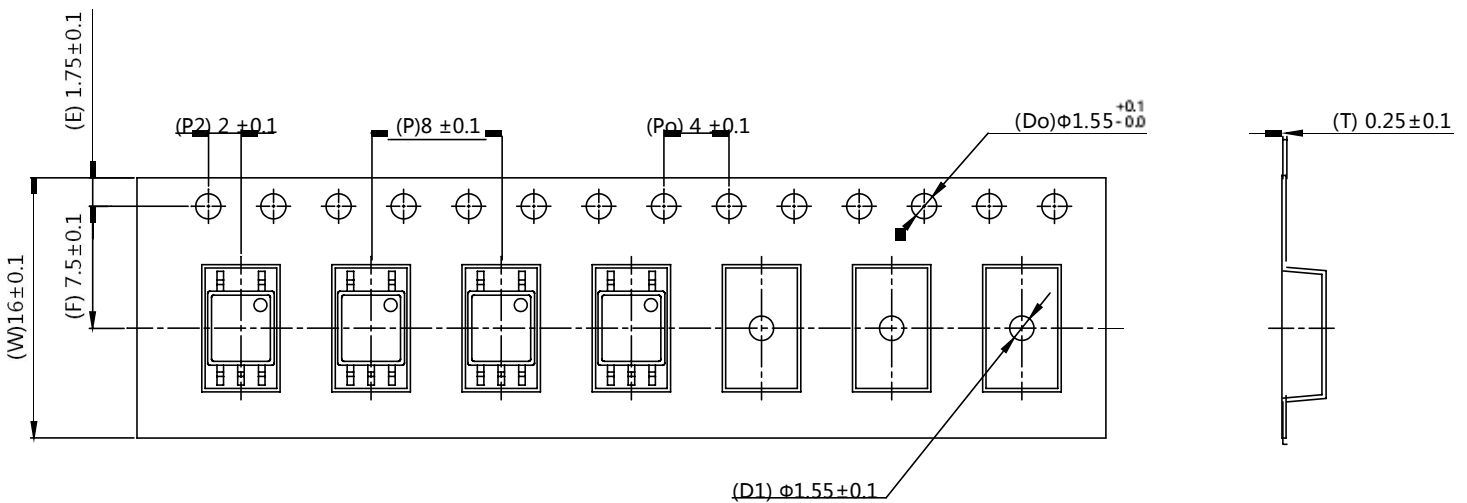
包装 Packing

■ 汇总表 Summary table

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
SOP6	卷盘 ($\phi 330$ mm 蓝盘)	1 千只/盘	2 盘/盒	10 盒/箱	450*390*0.1mm	340*60*340mm	620*360*365mm	首尾端空至少 200mm
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SOP6	Reel($\phi 330$ mm Blue)	1k pcs/reel	2Reel/box	10box/ctn	450*390*0.1mm	340*60*340mm	620*360*365mm	Guard band 200mm min.

■ 编带包装 Tape & Reel

- 1) 每卷数量：1000 只。
Qty/reel：1000 pcs.
- 2) 每箱数量：20000 只。
Qty/ctn：20000 pcs.
- 3) 内包装：每卷盘 1000 只。
Inner packing：1000pcs/reel.
- 4) 示意图 Schematic：



单位 Unit：mm

注意 Attention

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